

LFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Applicant(s): Douglas D. Coolbaugh, et al.

Examiner: Unassigned

Serial No: 10/711144

Art Unit: Unassigned

Filed: 8/27/04

Docket: BUR920040107US1 (17619)

For: MOS VARACTOR USING ISOLATION WELL **Dated:** August 6, 2004

Commissioner for Patents
Alexandria, VA 23313-1450

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with 37 C.F.R. §§ 1.97 and 1.98, it is requested that the following references, which are also listed on the attached Form PTO-1449, be made of record in the above-identified case.

1. European Patent Publication No. EP0902483 A1, published on March 17, 1999;
2. International Patent Publication No. WO 03/043079A1, published on May 22, 2003;
3. Joachim N. Burghartz, et al., "Integrated RF and Microwave Components in BiCMOS Technology", IEEE Transactions On Electron Devices, Vol. 43, No. 9, September 1996 (pp. 1559-1570); and
4. R.A. Moline, et al., "Ion-Implanted Hyperabrupt Junction Voltage Variable Capacitors", IEEE Transactions On Electron Devices, Vol. ED-19, No. 2, February 1972 (pp. 267-273).

CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8(a)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Box 1450, Alexandria, VA 22313-1450 on 8/31/04.

Dated: 8/31/04

P. H. de Haugis
P. H. de Haugis

Applicants are submitting copies of the above-cited references.

Inasmuch as this Information Disclosure Statement is being submitted in accordance with the schedule set out in 37 C.F.R. § 1.97(b), no statement or fee is required.

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'LSZ', with a long horizontal flourish extending to the right.

Leslie S. Szivos, Ph.D.
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LSS/sf
Enclosure PTO Form 1449

**LIST OF PRIOR ART
CITED BY APPLICANT**

(Use several sheets if necessary)



Atty. Docket No.
BUR920040107US1 (17619)

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Applicant
Douglas D. Coolbaugh, et al.

Filing Date
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Group
Unassigned

U.S. PATENT DOCUMENTS

EXAMINER INITIAL*		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (if appropriate)
	AA						
	AB						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
		EP0902483 A1	3/17/1999	EPO				
		WO 03/043079 A1	5/22/2003	PCT				

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

		Joachim N. Burghartz, et al., "Integrated RF and Microwave Components in BiCMOS Technology", IEEE Transactions On Electron Devices, Vol. 43, No. 9, September 1996 (pp. 1559-1570); and
		R.A. Moline, et al., "Ion-Implanted Hyperabrupt Junction Voltage Variable Capacitors", IEEE Transactions On Electron Devices, Vol. ED-19, No. 2, February 1972 (pp. 267-273).

EXAMINER

DATE CONSIDERED

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.